NSN 5961-00-145-3469

Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Metal
Terminal Length:
0.500 inches
Overall Height:
0.260 inches
Overall Diameter:
0.370 inches
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
60.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open and 5.0 breakdown voltage,
emitter-to-base, collector open all semiconductor
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
All transistor junction pattern arrangement: npn
Terminal Type And Quantity:
6 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0